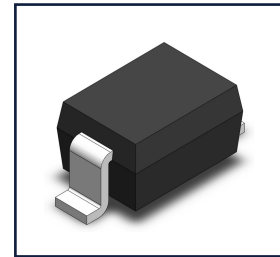


General description

These surge protection diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. These devices are ideal for situations where board space is at a premium.

Features and benefits

- Bidirectional ESD protection of one line
- Reverse stand-off voltage: 3.3V Max
- Low leakage current: nA Level
- Response time is typically < 1 ns
- Low clamping voltage: $V_C < 12\text{ V}$ @ $I_{PP} = 35\text{ A}$
- ESD Protection: 30kV(air)/ 30kV(contact) (IEC61000-4-2)
- RoHS compliant



SOD323

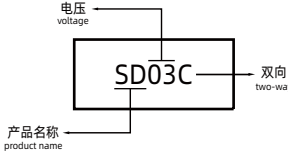
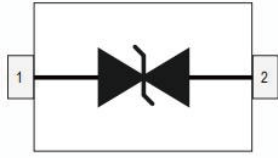
Application information

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers

Ordering information

Device	Package	Reel Size	Qty(PCS)
SD03C	SOD323	7 Inch	3000

Ordering information

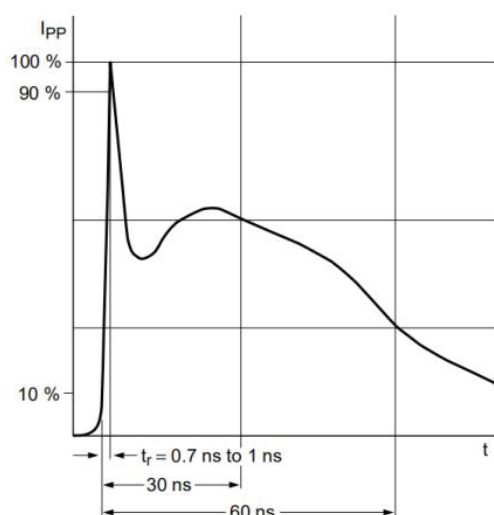
Marking	Naming rule	Graphic symbol
3/ε		

Maximum Ratings ($T_A = 25^\circ\text{C}$, unless otherwise specified)

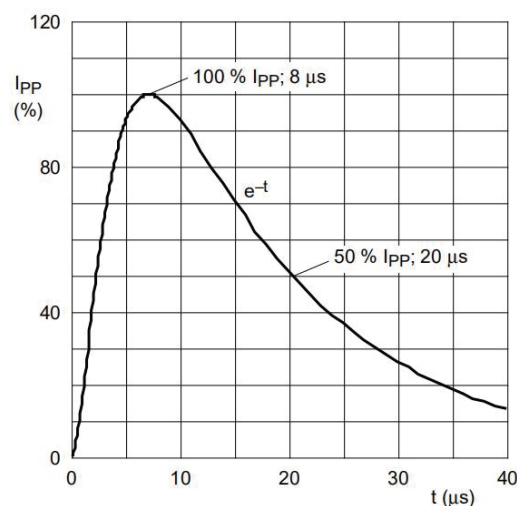
Parameter	Symbol	Value	Unit
Peak Pulse Power ($t_p = 8/20\mu\text{s}$)	P_{PPM}	450	W
Peak Pulse Current ($t_p = 8/20\mu\text{s}$)	I_{PPM}	35	A
Maximum lead temperature for soldering during 10s	T_L	260	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^\circ\text{C}$
Operating Temperature Range	T_{OP}	-40 to +125	$^\circ\text{C}$
ESD voltage IEC 61000-4-2 (air discharge)	V_{ESD}	30	kV
ESD voltage IEC 61000-4-2 (contact discharge)	V_{ESD}	30	kV

Electrical Characteristics ($T_A = 25^\circ\text{C}$, unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Reverse Working Voltage	V_{RWM}	--	--	3.3	V	
Breakdown Voltage	V_{BR}	4.0	--	6.0	V	$I_T = 1\text{mA}$
Leakage Current I_{Leak}	I_R	--	--	200	nA	$V_{RWM} = 3.3\text{V}$
Clamping Voltage	V_C	--	--	8.5	V	$I_{PP} = 20\text{A}, T_p = 8/20\mu\text{s}$
	V_C	--	--	12.0		$I_{PP} = 35\text{A}, T_p = 8/20\mu\text{s}$
Dynamic Resistance	R_{DYN}	--	0.1	--	Ω	$TLP = 0.2/100\text{ns}$
Junction Capacitance	C_J	--	66	70	pF	$V_R = 0\text{V}, f = 1\text{MHz}$



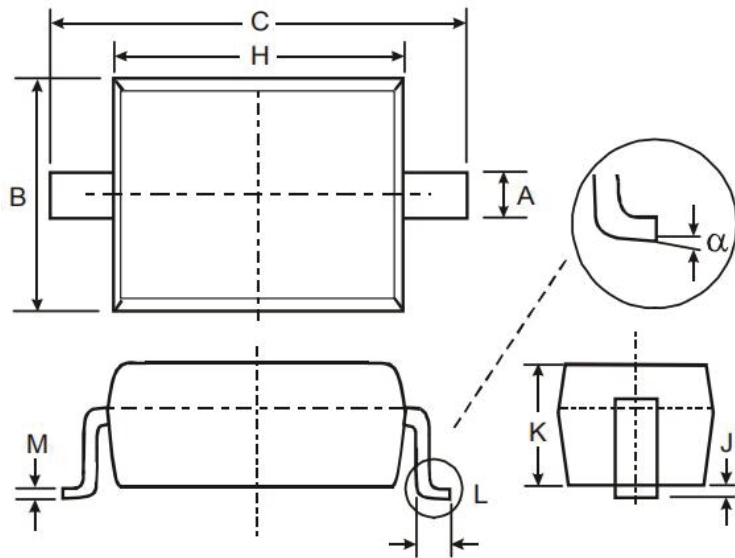
IEC61000-4-2 Waveform



IEC 61000-4-5 Waveform (8/20 μs pulse)

Package Outline Dimensions

SOD323



SYMBOL	MILLIMETERS	
	MIN	MAX
A	0.25	0.35
B	1.20	1.40
C	2.40	2.70
H	1.60	1.80
J	0.01	0.15
K	0.80	1.00
L	0.20	0.40
M	0.08	0.15
α	0°	8°

Soldering Footprint (mm)

